Thyristor Semiconductor Device - Page 1 of 1



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# Inclosure Material:

Ceramic and metal

# **Overall Length:**

1.646 inches

# Mounting Facility Quantity:

1

# Electrode Internally-electrically Connected To Case:

Anode

# **Mounting Method:**

Threaded stud

#### Overall Width Across Flats:

Between 0.544 inches and 0.563 inches

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

10.0 gate voltage, dc

#### Current Rating Per Characteristic:

40.00 amperes forward current, average of standard range and 175.00 amperes forward current, average preset

# Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius case

# Test Data Document:

18876-me43900200001 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# Terminal Type And Quantity:

2 tab, solder lug and 1 threaded stud

# Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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